NSN 5962-01-126-5112

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View Online at https://aerobasegroup.com/nsn/5962-01-126-5112

Body Length:

1.260 inches

Body Width:

Between 0.350 inches and 0.390 inches

Body Height:

0.210 inches

Maximum Power Dissipation Rating:

750.0 milliwatts

Operating Tempurature Range:

+0.0/+70.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Electrostatic sensitive and hermetically sealed and monolithic and electrically alterable and w/clock and bidirectional

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Metal oxide-semiconductor logic

Input Circuit Pattern:

19 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-35.0 volts power source and 3.0 volts power source

Time Rating Per Chacteristic:

100.00 nanoseconds propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Test Data Document:

07187-4045271 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

22 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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